

P-Channel Enhancement Mode MOSFET

Feature

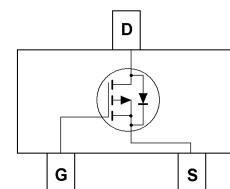
- 16V/-3A, $R_{DS(ON)} = 110\text{m}\Omega(\text{MAX})$ @ $V_{GS} = -4.5\text{V}$.
 $R_{DS(ON)} = 140\text{m}\Omega(\text{MAX})$ @ $V_{GS} = -2.5\text{V}$.
- Super High dense cell design for extremely low $R_{DS(ON)}$
- Reliable and Rugged
- SOT-23 for Surface Mount Package



SOT-23

Applications

- Power Management
- Portable Equipment and Battery Powered Systems.



Absolute Maximum Ratings

TA=25°C Unless Otherwise noted

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	-16	V
Gate-Source Voltage	V_{GS}	± 8	V
Drain Current-Continuous	I_D	-3	A

Electrical Characteristics

TA=25°C Unless Otherwise noted

Parameter	Symbol	Test Conditions	Min	Typ.	Max	Units
Off Characteristics						
Drain to Source Breakdown Voltage	BVDSS	$V_{GS}=0\text{V}, I_D=-250\mu\text{A}$	-16	-	-	V
Zero-Gate Voltage Drain Current	IDSS	$V_{DS}=-12\text{V}, V_{GS}=0\text{V}$	-	-	-5	μA
Gate Body Leakage Current, Forward	IGSSF	$V_{GS}=8\text{ V}, V_{DS}=0\text{V}$	-	-	100	nA
Gate Body Leakage Current, Reverse	IGSSR	$V_{GS}=-8\text{ V}, V_{DS}=0\text{V}$	-	-	-100	nA
On Characteristics						
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{GS}=V_{DS}, I_D=-250\mu\text{A}$	-0.45	-	-1.5	V
Static Drain-source	RDS(ON)	$V_{GS}=-4.5\text{V}, I_D =-3.0\text{A}$	-	--	110	$\text{m}\Omega$
On-Resistance		$V_{GS}=-2.5\text{V}, I_D =-2.0\text{A}$	-	--	140	$\text{m}\Omega$
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Voltage	VSD	$V_{GS}=0\text{V}, I_S=-1.25\text{A}$			-1.8	V

Typical Characteristics

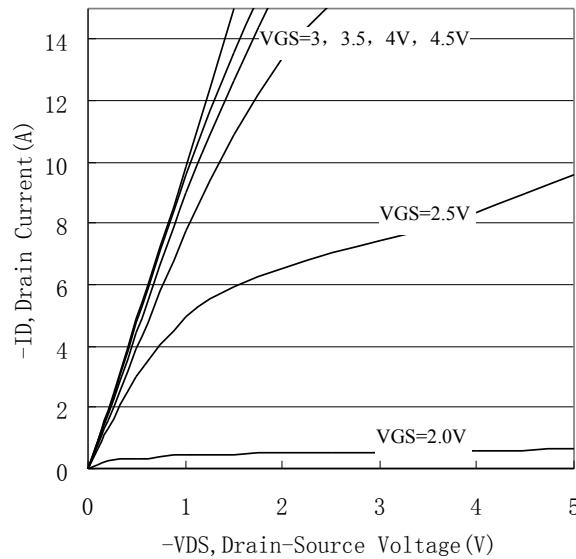


Figure 1. Output Characteristics

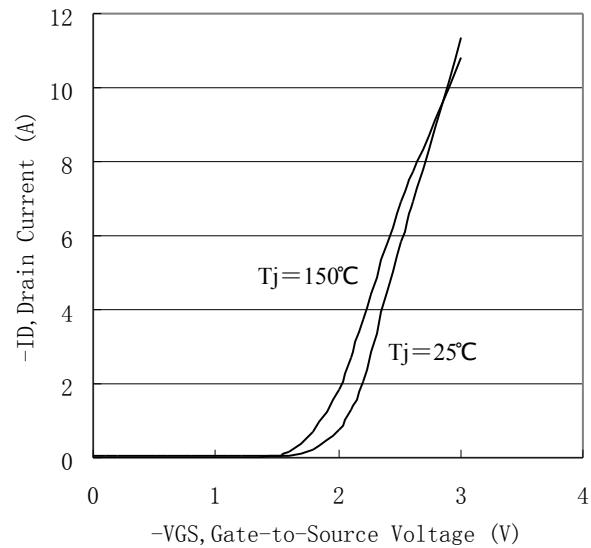


Figure 2. Transfer Characteristics

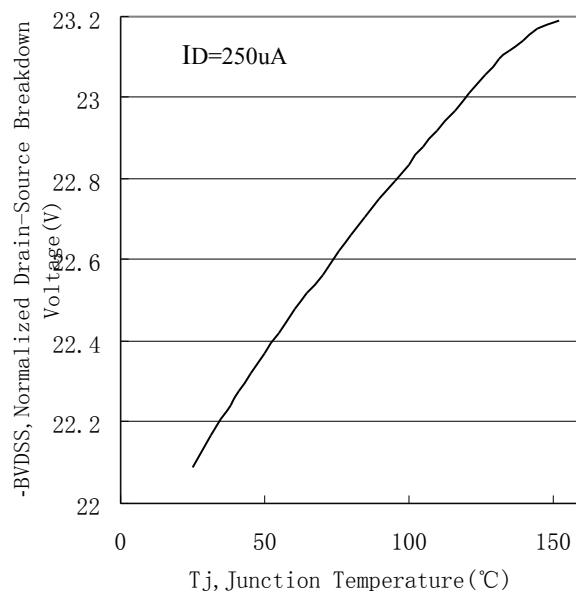


Figure 3. Breakdown Voltage Variation with Temperature

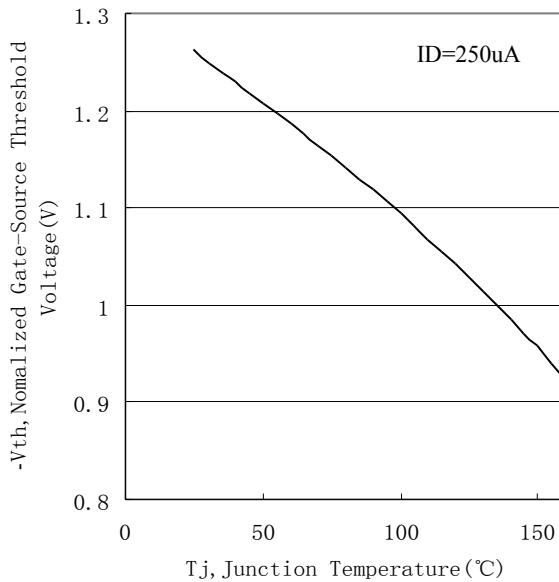


Figure 4. Gate Threshold Variation with Temperature

Typical Characteristics

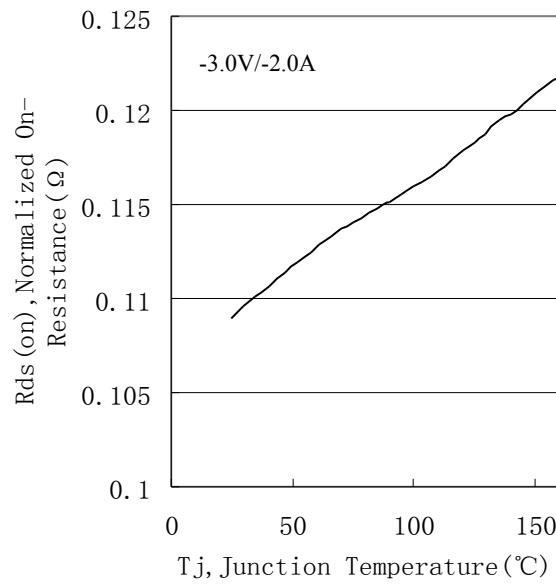


Figure 5. On-Resistance Variation with Temperature

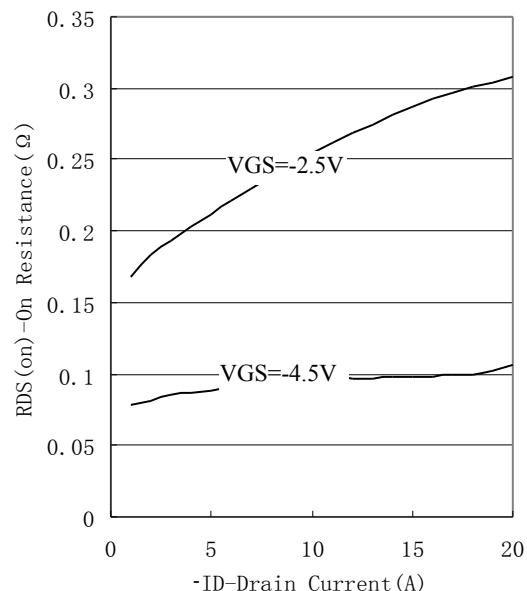


Figure 6. On-Resistance vs. Drain Current

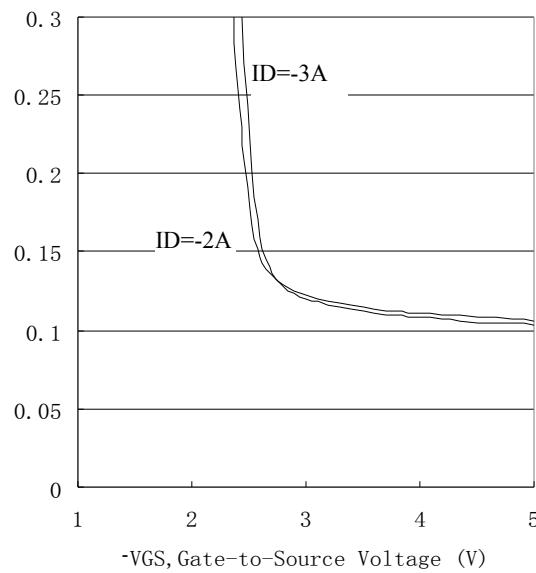


Figure 7. On-Resistance vs. Gate-to-Source Voltage

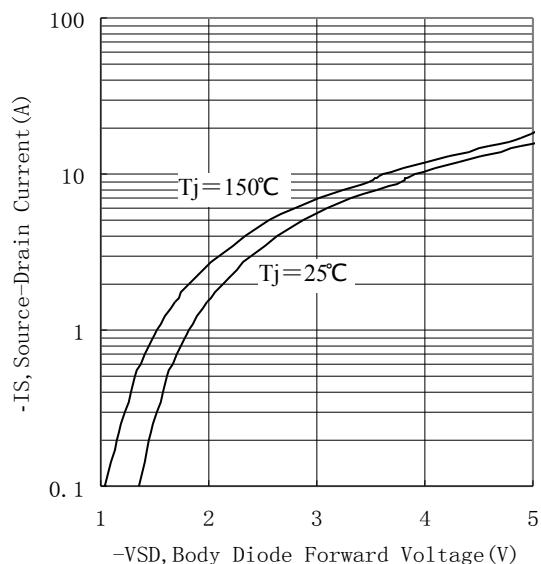


Figure 8 . Source-Drain Diode Forward

Package Outline Dimensions (UNIT: mm)

SOT-23

